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LM124/LM224/LM324/LM2902 Low Power Quad Operational Amplifiers

General Description

The LM124 series consists of four independent, high gain, internally frequency compensated operational amplifiers which were designed specifically to operate from a single power supply over a wide range of voltages. Operation from split power supplies is also possible and the low power supply current drain is independent of the magnitude of the power supply voltage.

Application areas include transducer amplifiers, DC gain blocks and all the conventional op amp circuits which now can be more easily implemented in single power supply systems. For example, the LM124 series can be directly operated off of the standard +5V power supply voltage which is used in digital systems and will easily provide the required interface electronics without requiring the additional $\pm 15V$ power supplies.

Unique Characteristics

- In the linear mode the input common-mode voltage range includes ground and the output voltage can also swing to ground, even though operated from only a single power supply voltage
- The unity gain cross frequency is temperature compensated
- The input bias current is also temperature compensated

Advantages

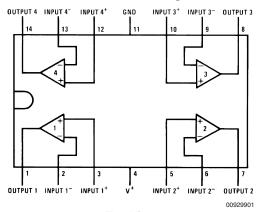
- Eliminates need for dual supplies
- Four internally compensated op amps in a single package
- Allows directly sensing near GND and V_{OUT} also goes to GND
- Compatible with all forms of logic
- Power drain suitable for battery operation

Features

- Internally frequency compensated for unity gain
- Large DC voltage gain 100 dB
- Wide bandwidth (unity gain) 1 MHz (temperature compensated)
- Wide power supply range:
 Single supply 3V to 32V
 or dual supplies ±1.5V to ±16V
- Very low supply current drain (700 µA) essentially independent of supply voltage
- Low input biasing current 45 nA (temperature compensated)
- Low input offset voltage 2 mV and offset current: 5 nA
- Input common-mode voltage range includes ground
- Differential input voltage range equal to the power supply voltage
- Large output voltage swing 0V to V⁺ 1.5V

Connection Diagrams

Dual-In-Line Package

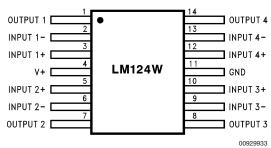


Top View

Order Number LM124J, LM124AJ, LM124J/883 (Note 2), LM124AJ/883 (Note 1), LM224J, LM224AJ, LM324M, LM324MX, LM324AM, LM324AMX, LM2902M, LM2902MX, LM324N, LM324AN, LM324AN, LM324MTX or LM2902N LM124AJRQML and LM124AJRQMLV(Note 3)

See NS Package Number J14A, M14A or N14A

Connection Diagrams (Continued)

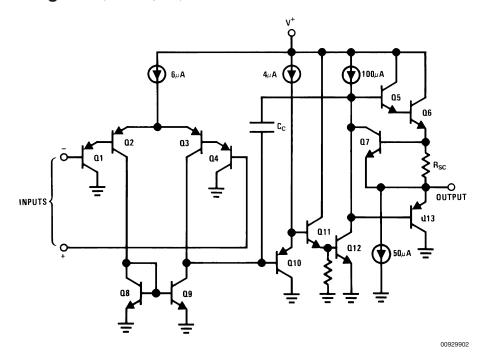


Order Number LM124AW/883, LM124AWG/883, LM124W/883 or LM124WG/883 LM124AWRQML and LM124AWRQMLV(Note 3) See NS Package Number W14B LM124AWGRQML and LM124AWGRQMLV(Note 3) See NS Package Number WG14A

Note 1: LM124A available per JM38510/11006 **Note 2:** LM124 available per JM38510/11005

Note 3: See STD Mil DWG 5962R99504 for Radiation Tolerant Device

Schematic Diagram (Each Amplifier)



Absolute Maximum Ratings (Note 12)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/

Distributors for availability and specifications.

	LM124/LM224/LM324	LM2902
	LM124A/LM224A/LM324A	
Supply Voltage, V ⁺	32V	26V
Differential Input Voltage	32V	26V
Input Voltage	-0.3V to +32V	-0.3V to $+26V$
Input Current		
$(V_{IN} < -0.3V)$ (Note 6)	50 mA	50 mA
Power Dissipation (Note 4)		
Molded DIP	1130 mW	1130 mW
Cavity DIP	1260 mW	1260 mW
Small Outline Package	800 mW	800 mW
Output Short-Circuit to GND		
(One Amplifier) (Note 5)		
$V^+ \le 15V$ and $T_A = 25^{\circ}C$	Continuous	Continuous
Operating Temperature Range		-40°C to +85°C
LM324/LM324A	0°C to +70°C	
LM224/LM224A	−25°C to +85°C	
LM124/LM124A	−55°C to +125°C	
Storage Temperature Range	-65°C to +150°C	-65°C to +150°C
Lead Temperature (Soldering, 10 seconds)	260°C	260°C
Soldering Information		
Dual-In-Line Package		
Soldering (10 seconds)	260°C	260°C
Small Outline Package		
Vapor Phase (60 seconds)	215°C	215°C
Infrared (15 seconds)	220°C	220°C
See AN-450 "Surface Mounting Methods and Their E	Effect on Product Reliability" for other methods	of soldering surface moun
devices.		

ESD Tolerance (Note 13) 250V 250V

Electrical Characteristics

 $V^+ = +5.0V$, (Note 7), unless otherwise stated

Parameter	Conditions		LM124A			LM224	Α	LM324A			Units
- Tarameter			Тур	Max	Min	Тур	Max	Min	Тур	Max	Offics
Input Offset Voltage	(Note 8) T _A = 25°C		1	2		1	3		2	3	mV
Input Bias Current	$I_{IN(+)}$ or $I_{IN(-)}$, $V_{CM} = 0V$,		20	50		40	80		45	100	nA
(Note 9)	$T_A = 25^{\circ}C$		20	30		40	00		40	100	IIA
Input Offset Current	$I_{IN(+)}$ or $I_{IN(-)}$, $V_{CM} = 0V$,		2	10		2	15		5	30	nA
	T _A = 25°C										
Input Common-Mode	V ⁺ = 30V, (LM2902, V ⁺ = 26V),	0	٧	/ ⁺ –1.5	0	٧	′+–1.5	0	V	′+–1.5	V
Voltage Range (Note	T _A = 25°C										
10)											
Supply Current	Over Full Temperature Range										
	R _L = ∞ On All Op Amps										mA
	V ⁺ = 30V (LM2902 V ⁺ = 26V)		1.5	3		1.5	3		1.5	3	
	V ⁺ = 5V		0.7	1.2		0.7	1.2		0.7	1.2	
Large Signal	$V^+ = 15V, R_L \ge 2k\Omega,$	50	100		50	100		25	100		V/mV
Voltage Gain	(V _O = 1V to 11V), T _A = 25°C										
Common-Mode	DC, $V_{CM} = 0V \text{ to } V^+ - 1.5V$,	70	85		70	85		65	85		dB

Electrical Characteristics (Continued) $V^+ = +5.0V$, (Note 7), unless otherwise stated

Davana		Conditions			LM124	IA	LM224A			LM324A			11
Paramet	er	Conditio	ns	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Units
Rejection Ratio		T _A = 25°C											
Power Supply $V^+ = 5V \text{ to } 30$		V ⁺ = 5V to 30V											
Rejection Ratio		(LM2902, V ⁺ = 5V to 2	26V),	65	100		65	100		65	100		dB
		T _A = 25°C											
Amplifier-to-Am	plifier	f = 1 kHz to 20 kHz, T	_A = 25°C		-120			-120			-120		dB
Coupling (Note	11)	(Input Referred)											
Output	Source	$V_{IN}^{+} = 1V, V_{IN}^{-} = 0V,$		20	40		20	40		20	40		
Current				20	40		20	40		20	40		
		$V^{+} = 15V, V_{O} = 2V, T_{A}$	_A = 25°C										mA
	Sink	$V_{IN}^- = 1V, V_{IN}^+ = 0V,$		10	20		10	20		10	20		
		$V^+ = 15V, V_O = 2V, T_A$	_A = 25°C										
		$V_{IN}^- = 1V, V_{IN}^+ = 0V,$		12	50		12	50		12	50		μΑ
		$V^{+} = 15V, V_{O} = 200 \text{ mV}, T_{A} = 25^{\circ}\text{C}$											
Short Circuit to Ground		(Note 5) $V^+ = 15V$, $T_A = 25^{\circ}C$			40	60		40	60		40	60	mA
Input Offset Voltage		(Note 8)				4			4			5	mV
V _{OS} Drift		$R_S = 0\Omega$			7	20		7	20		7	30	μV/°C
Input Offset Current		$I_{IN(+)} - I_{IN(-)}, V_{CM} = 0V$				30			30			75	nA
I _{OS} Drift		$R_S = 0\Omega$			10	200		10	200		10	300	pA/°C
Input Bias Curr	ent	$I_{IN(+)}$ or $I_{IN(-)}$			40	100		40	100		40	200	nA
Input Common-	Mode	$V^{+} = +30V$		0		V+-2	0		V ⁺ –2	0		V+-2	V
Voltage Range	(Note	$(LM2902, V^+ = 26V)$											
10)													
Large Signal		$V^+ = +15V (V_O Swing = $	= 1V to 11V)										
Voltage Gain	1	$R_L \ge 2 k\Omega$	T	25			25			15			V/mV
Output	V _{OH}	V ⁺ = 30V	$R_L = 2 k\Omega$	26			26			26			V
Voltage		(1.140000) (1.140000)	D 4010										-
Swing		(LM2902, V ⁺ = 26V)	$R_L = 10 \text{ k}\Omega$	27	28		27	28		27	28		
	V _{OL}	$V^+ = 5V$, $R_L = 10 \text{ k}\Omega$	1		5	20		5	20		5	20	mV
Output	Source	$V_O = 2V$	$V_{1N}^{+} = +1V,$	10	20		10	20		10	20		
Current			\ \ - \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \										
			$V_{IN}^{-} = 0V,$ $V^{+} = 15V$										mA
	Sink		V' = 15V $V_{IN}^{-} = +1V$,	10	15		5	8		5	8		-
	SIIIK		1	10	15)	0)	0		
			$V_{IN}^{+} = 0V,$ $V^{+} = 15V$										
			v - 15v										L

Electrical Characteristics

 $V^+ = +5.0V$, (Note 7), unless otherwise stated

Parameter	Conditions		LM124/LM224			LM32	4		Units		
raidilletei			Тур	Max	Min	Тур	Max	Min	Тур	Max	Ullits
Input Offset Voltage	(Note 8) T _A = 25°C		2	5		2	7		2	7	mV
Input Bias Current	$I_{IN(+)}$ or $I_{IN(-)}$, $V_{CM} = 0V$,		45	150		45	250		45	250	nA
(Note 9)	$T_A = 25^{\circ}C$		45	130		43	230		43	230	IIA
Input Offset Current	$I_{IN(+)}$ or $I_{IN(-)}$, $V_{CM} = 0V$,		3	30		5	50		5	50	nA
	$T_A = 25^{\circ}C$										
Input Common-Mode	V ⁺ = 30V, (LM2902, V ⁺ = 26V),	0	٧	/ ⁺ –1.5	0	٧	′ ⁺ –1.5	0	V	′ ⁺ –1.5	V
Voltage Range (Note	$T_A = 25^{\circ}C$										
10)											
					_						

Electrical Characteristics (Continued)

 $V^+ = +5.0V$, (Note 7), unless otherwise stated

Parameter		Conditions		LM	124/LI	VI224		LM32	4	LM2902			Units
	er	Conditions		Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Units
Supply Current		Over Full Temperature Range											
		R _L = ∞ On All Op Amps											mA
		$V^{+} = 30V (LM2902 V^{+})$	= 26V)		1.5	3		1.5	3		1.5	3	
		V ⁺ = 5V			0.7	1.2		0.7	1.2		0.7	1.2	
Large Signal		$V^+ = 15V, R_L \ge 2k\Omega,$		50	100		25	100		25	100		V/mV
Voltage Gain		$(V_O = 1V \text{ to } 11V), T_A$											
Common-Mode		DC, $V_{CM} = 0V$ to V^+ -	- 1.5V,	70	85		65	85		50	70		dB
Rejection Ratio		$T_A = 25^{\circ}C$											
Power Supply		$V^{+} = 5V \text{ to } 30V$											
Rejection Ratio		(LM2902, $V^+ = 5V$ to	26V),	65	100		65	100		50	100		dB
		$T_A = 25^{\circ}C$											
Amplifier-to-Am	plifier	f = 1 kHz to 20 kHz, 7	$\Gamma_A = 25^{\circ}C$		-120			-120			-120		dB
Coupling (Note	11)	(Input Referred)											
Output	Source	$V_{IN}^{+} = 1V, V_{IN}^{-} = 0V,$		20	40		20	40		20	40		
Current					10		20	-10			-10		
		$V^{+} = 15V, V_{O} = 2V, T$	_A = 25°C										mA
	Sink	$V_{IN}^- = 1V, V_{IN}^+ = 0V,$		10	20		10	20		10	20		
		$V^+ = 15V, V_O = 2V, T$	_A = 25°C										
		$V_{IN}^- = 1V, V_{IN}^+ = 0V,$		12	50		12	50		12	50		μA
		$V^+ = 15V, V_O = 200 \text{ n}$											
Short Circuit to	Short Circuit to Ground (Note 5) $V^+ = 15V$, $T_A = 25$		_ = 25°C		40	60		40	60		40	60	mA
Input Offset Vo	Itage	(Note 8)				7			9			10	mV
V _{OS} Drift		$R_S = 0\Omega$			7			7			7		μV/°C
Input Offset Cu	rrent	$I_{IN(+)} - I_{IN(-)}, V_{CM} = 0$	V			100			150		45	200	nA
I _{OS} Drift		$R_S = 0\Omega$			10			10			10		pA/°C
Input Bias Curr	ent	I _{IN(+)} or I _{IN(-)}			40	300		40	500		40	500	nA
Input Common-	Mode	$V^{+} = +30V$		0		V ⁺ -2	0		V ⁺ -2	0		V+-2	V
Voltage Range	(Note	$(LM2902, V^+ = 26V)$											
10)													
Large Signal		$V^+ = +15V (V_O Swing)$	= 1V to 11V)										
Voltage Gain		$R_L \ge 2 k\Omega$		25			15			15			V/mV
Output	V _{OH}	V ⁺ = 30V	$R_L = 2 k\Omega$	26			26			22			V
Voltage		(,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,											-
Swing		(LM2902, V ⁺ = 26V)	$R_L = 10 \text{ k}\Omega$	27	28		27	28		23	24		
	V _{OL}	$V^{+} = 5V, R_{L} = 10 \text{ k}\Omega$			5	20		5	20		5	100	mV
Output	Source	$V_O = 2V$	$V_{1N}^{+} = +1V,$	10	20		10	20		10	20		
Current			\ \ - \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \										
			$V_{IN}^{-} = 0V,$ $V^{+} = 15V$										mA
	Cimi			-			<u> </u>			-			1
	Sink		$V_{1N}^{-} = +1V,$	5	8		5	8		5	8		
			$V_{IN}^{+} = 0V,$ $V^{+} = 15V$										
			V ⁺ = 15V										

Note 4: For operating at high temperatures, the LM324/LM324A/LM2902 must be derated based on a +125°C maximum junction temperature and a thermal resistance of 88°C/W which applies for the device soldered in a printed circuit board, operating in a still air ambient. The LM224/LM224A and LM124/LM124A can be derated based on a +150°C maximum junction temperature. The dissipation is the total of all four amplifiers — use external resistors, where possible, to allow the amplifier to saturate of to reduce the power which is dissipated in the integrated circuit.

Note 5: Short circuits from the output to V⁺ can cause excessive heating and eventual destruction. When considering short circuits to ground, the maximum output current is approximately 40 mA independent of the magnitude of V⁺. At values of supply voltage in excess of +15V, continuous short-circuits can exceed the power dissipation ratings and cause eventual destruction. Destructive dissipation can result from simultaneous shorts on all amplifiers.

Note 6: This input current will only exist when the voltage at any of the input leads is driven negative. It is due to the collector-base junction of the input PNP transistors becoming forward biased and thereby acting as input diode clamps. In addition to this diode action, there is also lateral NPN parasitic transistor action

Electrical Characteristics (Continued)

on the IC chip. This transistor action can cause the output voltages of the op amps to go to the V^+ voltage level (or to ground for a large overdrive) for the time duration that an input is driven negative. This is not destructive and normal output states will re-establish when the input voltage, which was negative, again returns to a value greater than -0.3V (at 25°C).

Note 7: These specifications are limited to $-55^{\circ}C \le T_A \le +125^{\circ}C$ for the LM124/LM124A. With the LM224/LM224A, all temperature specifications are limited to $-25^{\circ}C \le T_A \le +85^{\circ}C$, the LM324/LM324A temperature specifications are limited to $0^{\circ}C \le T_A \le +70^{\circ}C$, and the LM2902 specifications are limited to $-40^{\circ}C \le T_A \le +85^{\circ}C$.

Note 8: $V_O \simeq 1.4V$, $R_S = 0\Omega$ with V⁺ from 5V to 30V; and over the full input common-mode range (0V to V⁺ - 1.5V) for LM2902, V⁺ from 5V to 26V.

Note 9: The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of the output so no loading change exists on the input lines.

Note 10: The input common-mode voltage of either input signal voltage should not be allowed to go negative by more than 0.3V (at 25°C). The upper end of the common-mode voltage range is V⁺ – 1.5V (at 25°C), but either or both inputs can go to +32V without damage (+26V for LM2902), independent of the magnitude of V⁺

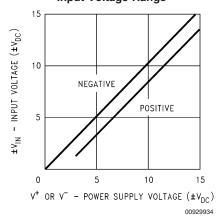
Note 11: Due to proximity of external components, insure that coupling is not originating via stray capacitance between these external parts. This typically can be detected as this type of capacitance increases at higher frequencies.

Note 12: Refer to RETS124AX for LM124A military specifications and refer to RETS124X for LM124 military specifications.

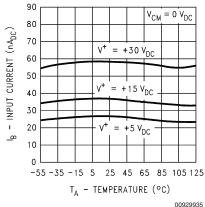
Note 13: Human body model, 1.5 k Ω in series with 100 pF.

Typical Performance Characteristics

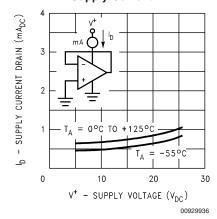




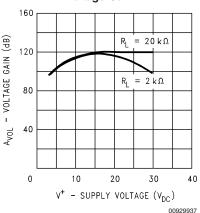
Input Current



Supply Current

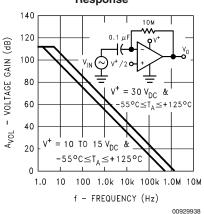


Voltage Gain

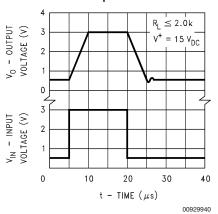


Typical Performance Characteristics (Continued)

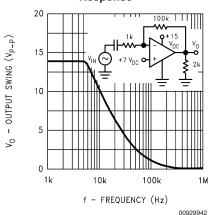
Open Loop Frequency Response



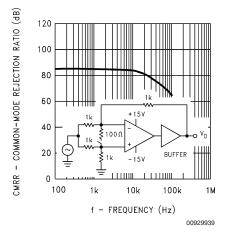
Voltage Follower Pulse Response



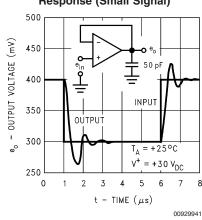
Large Signal Frequency Response



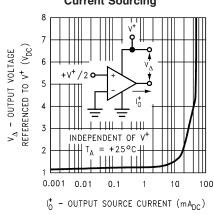
Common Mode Rejection Ratio



Voltage Follower Pulse Response (Small Signal)



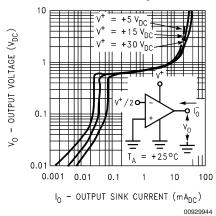
Output Characteristics Current Sourcing



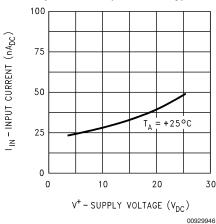
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Typical Performance Characteristics (Continued)

Output Characteristics Current Sinking



Input Current (LM2902 only)



T_A - TEMPERATURE (°C)

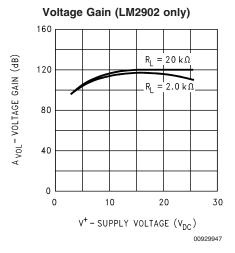
25 45 65 85 105 125

-15 5

Current Limiting

90 80

OUTPUT CURRENT (mA_{DC})



Application Hints

The LM124 series are op amps which operate with only a single power supply voltage, have true-differential inputs, and remain in the linear mode with an input common-mode voltage of 0 $V_{\rm DC}.$ These amplifiers operate over a wide range of power supply voltage with little change in performance characteristics. At $25\,^{\circ}\text{C}$ amplifier operation is possible down to a minimum supply voltage of $2.3~V_{\rm DC}.$

The pinouts of the package have been designed to simplify PC board layouts. Inverting inputs are adjacent to outputs for all of the amplifiers and the outputs have also been placed at the corners of the package (pins 1, 7, 8, and 14).

Precautions should be taken to insure that the power supply for the integrated circuit never becomes reversed in polarity or that the unit is not inadvertently installed backwards in a test socket as an unlimited current surge through the resulting forward diode within the IC could cause fusing of the internal conductors and result in a destroyed unit.

Large differential input voltages can be easily accommodated and, as input differential voltage protection diodes are not needed, no large input currents result from large differential input voltages. The differential input voltage may be larger than V⁺ without damaging the device. Protection

should be provided to prevent the input voltages from going negative more than –0.3 $V_{\rm DC}$ (at 25°C). An input clamp diode with a resistor to the IC input terminal can be used.

To reduce the power supply drain, the amplifiers have a class A output stage for small signal levels which converts to class B in a large signal mode. This allows the amplifiers to both source and sink large output currents. Therefore both NPN and PNP external current boost transistors can be used to extend the power capability of the basic amplifiers. The output voltage needs to raise approximately 1 diode drop above ground to bias the on-chip vertical PNP transistor for output current sinking applications.

For ac applications, where the load is capacitively coupled to the output of the amplifier, a resistor should be used, from the output of the amplifier to ground to increase the class A bias current and prevent crossover distortion.

Where the load is directly coupled, as in dc applications, there is no crossover distortion.

Capacitive loads which are applied directly to the output of the amplifier reduce the loop stability margin. Values of 50 pF can be accommodated using the worst-case noninverting unity gain connection. Large closed loop gains or resistive isolation should be used if larger load capacitance must be driven by the amplifier.

Application Hints (Continued)

The bias network of the LM124 establishes a drain current which is independent of the magnitude of the power supply voltage over the range of from 3 $V_{\rm DC}$ to 30 $V_{\rm DC}.$

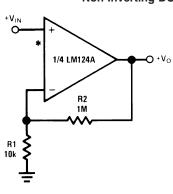
Output short circuits either to ground or to the positive power supply should be of short time duration. Units can be destroyed, not as a result of the short circuit current causing metal fusing, but rather due to the large increase in IC chip dissipation which will cause eventual failure due to excessive junction temperatures. Putting direct short-circuits on more than one amplifier at a time will increase the total IC power dissipation to destructive levels, if not properly protected with external dissipation limiting resistors in series with the output leads of the amplifiers. The larger value of

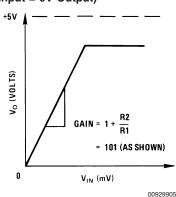
output source current which is available at 25°C provides a larger output current capability at elevated temperatures (see typical performance characteristics) than a standard IC op amp.

The circuits presented in the section on typical applications emphasize operation on only a single power supply voltage. If complementary power supplies are available, all of the standard op amp circuits can be used. In general, introducing a pseudo-ground (a bias voltage reference of $V^+/2)$ will allow operation above and below this value in single power supply systems. Many application circuits are shown which take advantage of the wide input common-mode voltage range which includes ground. In most cases, input biasing is not required and input voltages which range to ground can easily be accommodated.

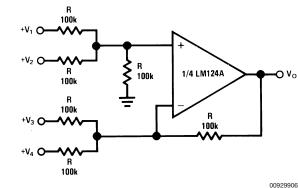
Typical Single-Supply Applications $(V^+ = 5.0 V_{DC})$

Non-Inverting DC Gain (0V Input = 0V Output)



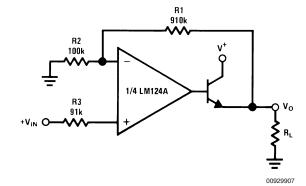


DC Summing Amplifier $(V_{IN'S} \ge 0 \ V_{DC})$ and $V_O \ge V_{DC}$



Where: $V_0 = V_1 + V_2 - V_3 - V_4$ $(V_1 + V_2) \ge (V_3 + V_4)$ to keep $V_0 > 0$ V_{DC}

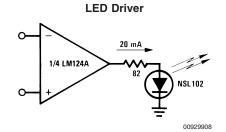
Power Amplifier



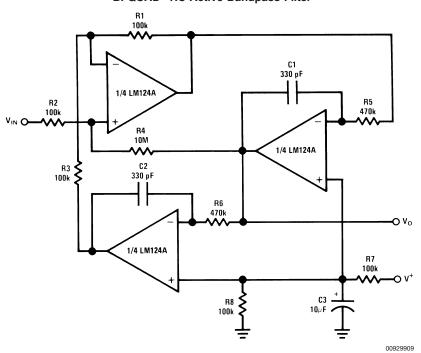
 $V_0 = 0 V_{DC}$ for $V_{IN} = 0 V_{DC}$ $A_V = 10$

^{*}R not needed due to temperature independent I_{IN}

Typical Single-Supply Applications (V⁺ = 5.0 V_{DC}) (Continued)



"BI-QUAD" RC Active Bandpass Filter



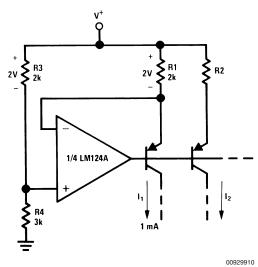
 $f_0 = 1 \text{ kHz}$

Q = 50

 $A_V = 100 (40 dB)$

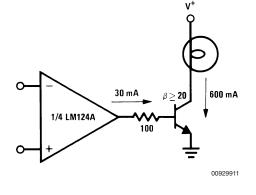
10

Fixed Current Sources



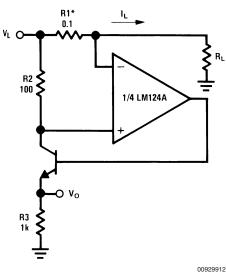
 $I_2 = \left(\frac{R1}{R2}\right)I_1$

Lamp Driver



Typical Single-Supply Applications (V+ = 5.0 V_{DC}) (Continued)

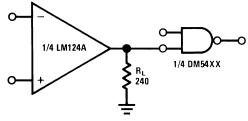
Current Monitor



$$V_1 \leq V^+ - 2V$$

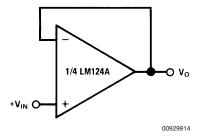
*(Increase R1 for I_L small)

Driving TTL



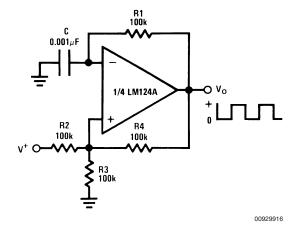
00929913

Voltage Follower

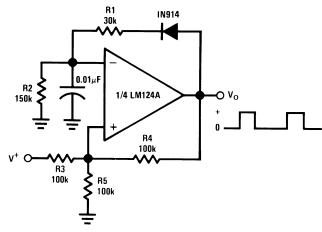


Pulse Generator R1 1M IN914 IN914 100k $\mathbf{0.001}\mu\mathbf{F}$ 1/4 LM124A $o v_o$ R3 100k R5 100k R4 100k 00929915

Squarewave Oscillator



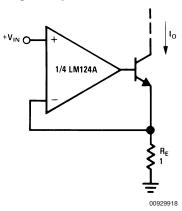
Pulse Generator



00929917

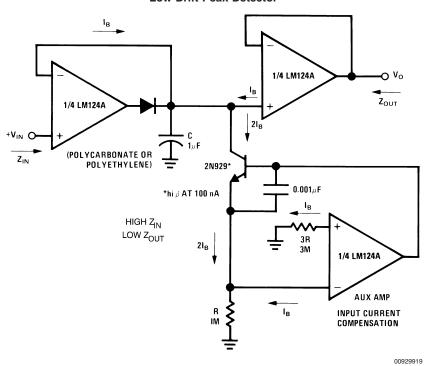
Typical Single-Supply Applications (V⁺ = 5.0 V_{DC}) (Continued)

High Compliance Current Sink



 $I_O = 1$ amp/volt V_{IN} (Increase R_E for I_o small)

Low Drift Peak Detector

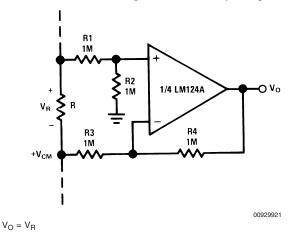


Typical Single-Supply Applications ($V^+ = 5.0 V_{DC}$) (Continued)

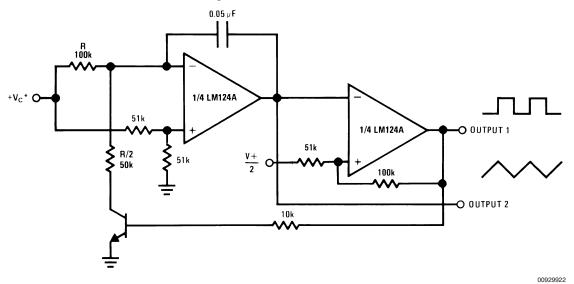
Comparator with Hysteresis

+V_{IN} O V_O 1/4 LM124A V_O +V_{REF} O V_O 00829820

Ground Referencing a Differential Input Signal

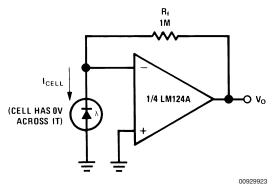


Voltage Controlled Oscillator Circuit



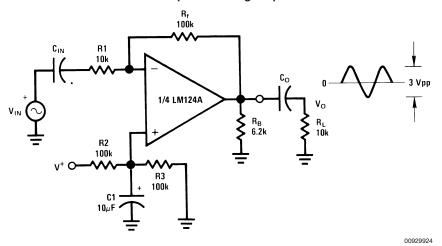
*Wide control voltage range: 0 $V_{DC} \le V_{C} \le 2$ (V⁺ -1.5 V_{DC})

Photo Voltaic-Cell Amplifier



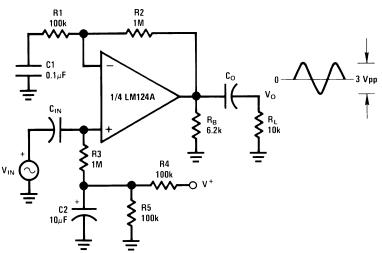
Typical Single-Supply Applications (V⁺ = 5.0 V_{DC}) (Continued)

AC Coupled Inverting Amplifier



$$A_V = \frac{R_f}{R1}$$
 (As shown, $A_V = 10$)

AC Coupled Non-Inverting Amplifier



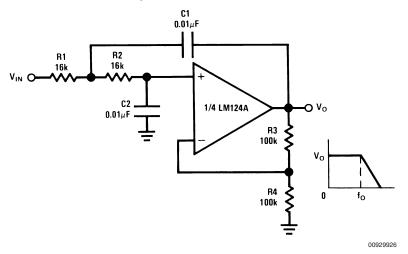
00929925

$$A_V = 1 + \frac{R2}{R1}$$

$$A_V = 11 \text{ (As shown)}$$

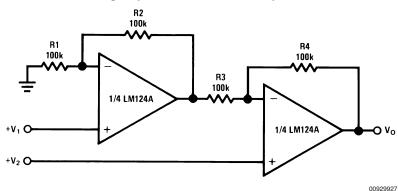
Typical Single-Supply Applications ($V^+ = 5.0 V_{DC}$) (Continued)

DC Coupled Low-Pass RC Active Filter



 $f_O = 1 \text{ kHz}$ Q = 1 $A_V = 2$

High Input Z, DC Differential Amplifier

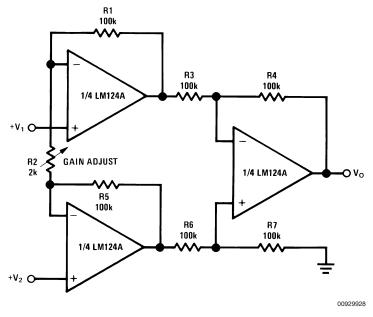


For $\frac{R1}{R2} = \frac{R4}{R3}$ (CMRR depends on this resistor ratio match)

$$V_{O} = 1 + \frac{R4}{R3}(V_{2} - V_{1})$$
As shown: $V_{O} = 2(V_{2} - V_{1})$

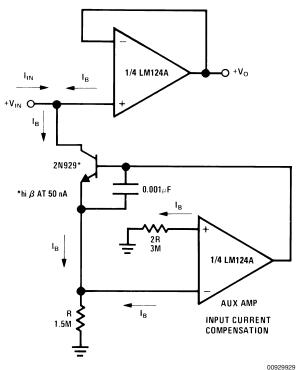
Typical Single-Supply Applications (V⁺ = 5.0 V_{DC}) (Continued)

High Input Z Adjustable-Gain DC Instrumentation Amplifier

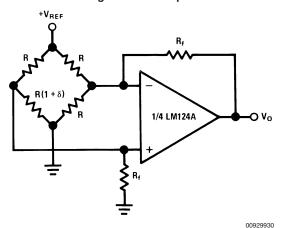


If R1 = R5 & R3 = R4 = R6 = R7 (CMRR depends on match)
$$V_O=1+\frac{2R1}{R2}(V_2-V_1)$$
 As shown $V_O=$ 101 (V_2-V_1)

Using Symmetrical Amplifiers to Reduce Input Current (General Concept)



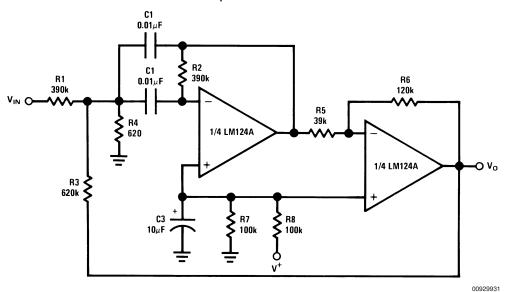
Bridge Current Amplifier



For $\delta <<$ 1 and $R_f >> R$ $V_O \cong V_{REF} \left(\frac{\delta}{2}\right) \frac{R_f}{R}$

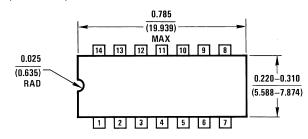
Typical Single-Supply Applications ($V^+ = 5.0 V_{DC}$) (Continued)

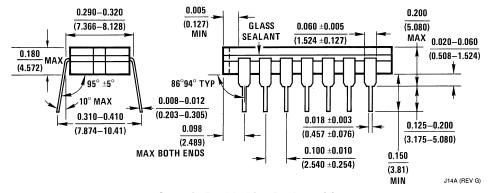
Bandpass Active Filter



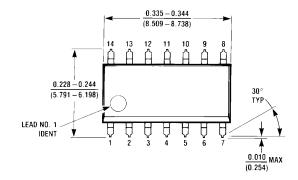
 $f_O = 1 \text{ kHz}$ Q = 25

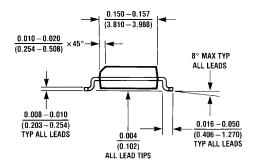
Physical Dimensions inches (millimeters) unless otherwise noted

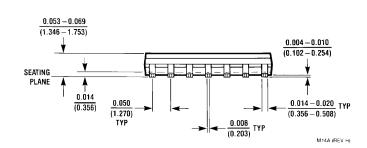




Ceramic Dual-In-Line Package (J)
Order Number JL124ABCA, JL124BCA, JL124ASCA, JL124SCA, LM124J,
LM124AJ, LM124AJ/883, LM124J/883, LM224J, LM224AJ or LM324J
NS Package Number J14A

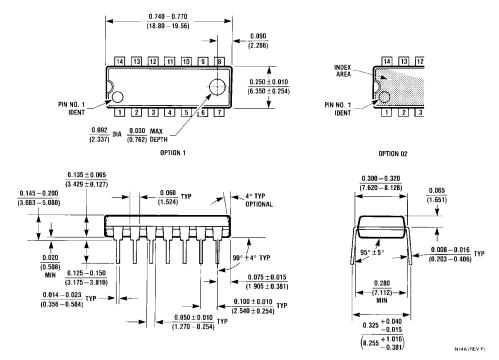




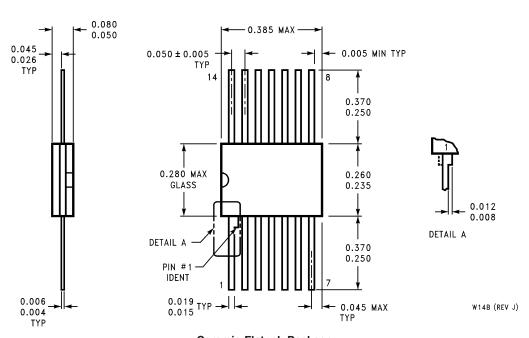


MX S.O. Package (M)
Order Number LM324M, LM324MX, LM324AM, LM324AMX, LM2902M or LM2902MX
NS Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

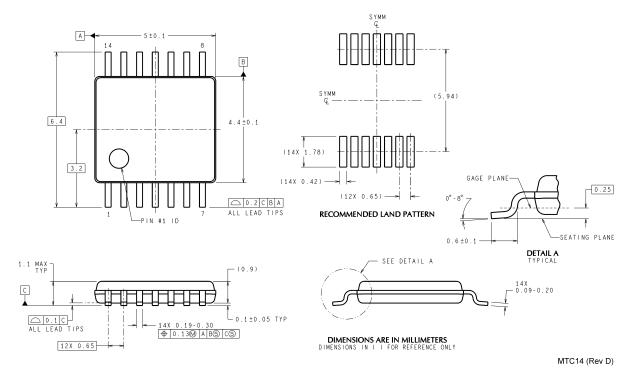


Molded Dual-In-Line Package (N)
Order Number LM324N, LM324AN or LM2902N
NS Package Number N14A



Ceramic Flatpak Package
Order Number JL124ABDA, JL124ABZA, JL124ASDA, JL124BDA, JL124BZA,
JL124SDA, LM124AW/883, LM124AWG/883, LM124W/883 or LM124WG/883
NS Package Number W14B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Pin TSSOP
Order NumberLM324MT or LM324MTX
NS Package Number MTC14

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- A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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